

Modeling ionic conduction

by Akram La Kilo

Submission date: 01-Aug-2019 10:42AM (UTC+0700)

Submission ID: 1156672252

File name: Akram-La-Kilo-Modeling-ionic-conduction-in-Bi2VO55.pdf (446.82K)

Word count: 2185

Character count: 11488

Modeling Ionic Conduction in γ -Bi₂VO_{5.5}

Akram I. Kilo¹, Bambang Prijamboedi¹, Muhamad A. Martoprawiro¹, and Ismunandar^{1,2}

¹Inorganic and Physical Chemistry Division, Bandung Institute of Technology, Bandung, Indonesia

²Corresponding Author, E-mail: ismu@chem.itb.ac.id

Abstract— γ -Bi₂VO_{5.5} family oxides has potential to play important role in solid oxide fuel cell, especially as the electrolyte due to their high ionic conductivity. In this work, oxide conduction in γ -Bi₂VO_{5.5} is modeled based on bond valence sum (BVS) method. In γ -Bi₂VO_{5.5}, there are oxide vacancies at the equatorial position in the perovskite-like layers. These vacancies can facilitate oxide movement. The γ -Bi₂VO_{5.5} model was built in a primitive structure with the entire V coordination in one layer are tetrahedron and entire V coordination in the next layer are octahedron. Oxygen movement, based on BVS result, mainly occurs in equatorial site i.e. on [140] direction. The minimum achieved BVS value was 1.320, which is considered as a site that has large cavity and facilitates oxygen hopping.

Keyword: γ -Bi₂VO_{5.5}, BVS, oxygen conduction.

I. INTRODUCTION

Solid electrolyte materials with high oxide ion conductivity at low temperature are intensively investigated in order to have solid oxide fuel cell (SOFC) capable of operating at low temperature. One of oxide material that has high oxide ion conductivity is γ -Bi₂VO_{5.5}. As comparison to the materials widely used as a solid electrolyte material, such as yttria stabilized zirconia (YSZ), γ -Bi₂VO_{5.5} has ionic conductivity of $1 \times 10^{-2} \text{ Scm}^{-1}$, which is around three orders of magnitude larger than YSZ at same temperature of 300 °C [1]. Therefore γ -Bi₂VO_{5.5} has potential application as electrolyte in SOFC working at low temperature.

The structure of Bi₂VO_{5.5} can be derived from Bi₂WO₆ and γ -Bi₂MoO₆ by formation of oxide vacancies in the metal oxide layers; thus the compound can be formulated (Bi₂O₂)(VO_{3.5})_{0.5}, where is the corresponding to intrinsic oxide vacancy [1, 2]. The Bi₂VO_{5.5} goes to several structural transformations and known has several polymorphs but essentially, there are only three main polymorphs, namely α , β , and γ with the transformations: $\alpha \rightarrow \beta$ at 447 °C and $\beta \rightarrow \gamma$ at 567 °C. The structures of α and β -phases are more ordered, larger in unit cell, and have lower conductivity. At the high temperature, γ -phase is formed and has maximum conductivity of 0.2 Scm^{-1} at 670 °C [3].

Experimental studies on the oxide conductivity of γ -Bi₂VO_{5.5} have been reported elsewhere [4]. However, the experimental study could not reveal the detail of the mechanism of ionic conduction. Abraham and Krok proposed oxide conduction mechanism which was applied only to BIMEVOX with ME is divalent metal, and derived from crystallographic data [5]. In

our knowledge, the conduction mechanism in parent structure of BIMEVOX, γ -Bi₂VO_{5.5}, has not been reported yet. Computational studies could be used to study the detail of ionic conductivity mechanism in the atomic level. Some computation study on the layered structure of Aurivillius phases similar to γ -Bi₂VO_{5.5} has been carried out and reported [6]. It could reveal defect energies and maximum dopant concentrations in Aurivillius as ferroelectric material.

Here, we report the computational study of γ -Bi₂VO_{5.5} structure that cover trajectory of oxide in γ -Bi₂VO_{5.5}. The study was aimed to investigate the oxide pathways that are possible in the γ -Bi₂VO_{5.5} structure via vacancy defect in perovskite-like layer.

II. EXPERIMENTAL METHOD

In this study, oxide migration in γ -Bi₂VO_{5.5} is calculated using by method of bond valence sum (BVS). BVS method is empirical model which predict oxidation state based on distances with neighbor atoms. The rule of bond valence is formulated:

$$V_i = \sum S_{ij} \quad (1)$$

The equation above shows the empirical relationship between bond valence and bond length or the distance between ions i and j (R_{ij}) which is defined:

$$V_{ij} = \exp\left(\frac{R_0 - R_{ij}}{b}\right) \quad (2)$$

where R_0 is a constant and b is universal constant which is 0.173. In this work, the value of R_0 and b are 0.516 Å and 1.171 Å, respectively.

The method has been successfully used to model the movement of cations in solid materials, such as Na⁺ in the NASICON (sodium super ionic conductor) and K⁺ in KFeAs₂O₇ [7, 8]. In this study, movement or geometry conduction for oxide in γ -Bi₂VO_{5.5} structure is predicted by using the BVS method as has been performed by JUMPITER [9].

γ -Bi₂VO_{5.5} structure which is built in this work are an simple model that can represent the structure, especially by paying attention the possibility of various vanadium coordination environment in the perovskite-like layer. Here, we built model of γ -Bi₂VO_{5.5} as simple as possible to get insight the oxide conduction of γ -Bi₂VO_{5.5}. This model is a primitive structure for one unit cell of γ -Bi₂VO_{5.5} where perovskite-like layers

1 have two different vanadium coordinations, namely tetrahedron and octahedron. In the middle the layer, V coordinations are entire tetrahedron, meanwhile, the upper and lower perovskite-like layers of γ -Bi₂VO_{5.5} have entirely octahedral coordination.

III. RESULT AND DISCUSSION

Structures of model were created based on γ -Bi₂VO_{5.5} structure reported by Mairesse *et al.* as depicted in Figure 1. [10]. The γ -Bi₂VO_{5.5} is tetragonal with space group is *I4/mmm*, and cell unit dimension is $a = 3.99176(4)$, $b = 3.99176(4)$, and $c = 15.4309(3)$ Å. The structure has high symmetry and contains oxygen vacancy in perovskite-like layer. Environment of the V⁵⁺ coordinations in perovskite-like layer are recognized as octahedron, tetrahedron, trigonal bipyramid, and tetragonal pyramid with interatomic distances compatible with O atomic size. Based on the vanadium coordination environment, we built a model structure of γ -Bi₂VO_{5.5} with *P1* space group by creating oxide vacancies at the equatorial site, so the perovskite-like layer becomes entire tetrahedrons, and other layers were octahedron (Figure 2). The structure is far from the real structure of γ -Bi₂VO_{5.5}, however we expect that an insight of the role of non octahedron coordination in the oxide conduction could be obtained.

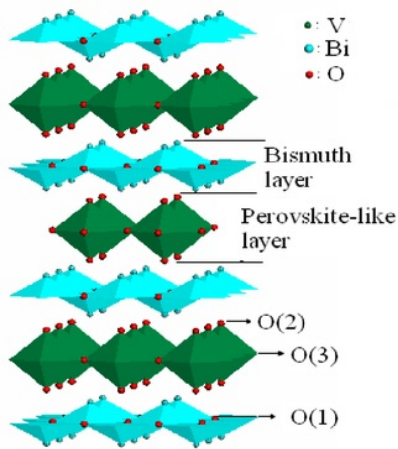


Figure 1. The refined crystal structures of γ -Bi₂VO_{5.5}, vacancies in perovskite-like layers were not shown. O(3) and O(2) each are equatorial and apical oxides, respectively.

III.1 Trajectory of Oxide Conduction in γ -Bi₂VO_{5.5}

To find a most possible the pathway in the γ -Bi₂VO_{5.5} structure, we do the calculations using by the bond valence sum. As a preliminary step, the structure of γ -Bi₂VO_{5.5} is optimized. Geometry optimization of model carried out by Density Functional Theory (DFT) method using by the CASTEP program.

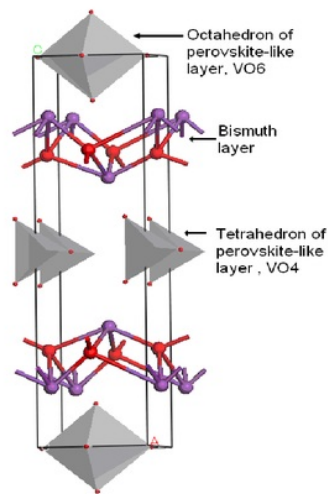


Figure 2. Model of γ -Bi₂VO_{5.5} structures; vacancies in equatorial site of perovskite-like layers (tetrahedron coordinations, VO₄) were not shown. The other coordinations of perovskite-like layers (upper and below) are octahedron, VO₆.

The activation energy of oxide to move to vacant position is calculated using by *ab initio* method. The results showed that oxide ion migration into vacant positions in the perovskite-like layer requires activation energy of 0.38 eV. This result is in a good agreement to experimental results [4, 11-13], although, Joubert *et al.* reported a value of 0.19 eV [14]. Based on the activation energy result, the structure is a good model for *ab initio* methods as well as bond valence sum, but not for molecular dynamic.

The oxide conduction was very difficult as indicated by maximum BVS value was very high, reaching twice the valence of oxygen. On the upper and lower perovskite-like layers of γ -Bi₂VO_{5.5} are entirely octahedral coordination, thus hopping oxygen is not possible since there is no vacancy.

Pathway of oxide in the structure was modeled by using the JUMPIER software based on bond valence sum on various directions. Oxide movements into the apical site reached potential barrier very quickly with BVS of 11.758 at 0.131 Å distance. Therefore, oxide movement was calculated in equatorial site, that could be modeled on the directions of [100], [010], and *[ab0]*. Bond valence sum of trajectory O(3) in the these directions is shown in Figure 3. It could be seen that the movement of oxide are difficult into the directions of *a* and *b*. The covered oxide migration distances in [100] and [010] directions do not exceed 1.2 and 0.4 Å, respectively. The easy conduction path of ionic conductivity in the γ -Bi₂VO_{5.5} is in the direction of *ab*, as given in the Figure 4.

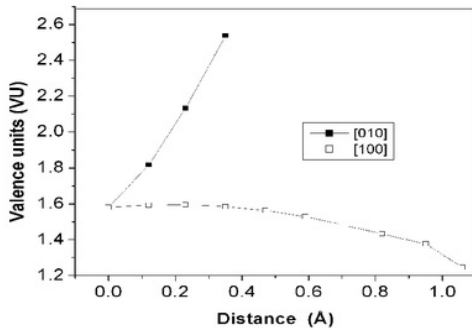


Figure 3. BVS of oxide on [100] and [010] directions in the perovskite-like layer of γ - $\text{Bi}_2\text{VO}_{5.5}$. Distances of oxide migration in [100] and [010] directions do not exceed 1.2 and 0.4 Å, respectively.

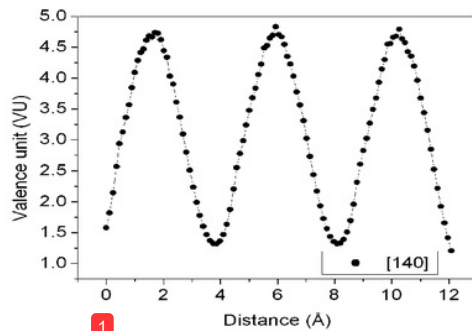


Figure 4. BVS of oxide on [140] direction in the perovskite-like layer of γ - $\text{Bi}_2\text{VO}_{5.5}$. Hopping distance of oxide is 3.86 Å.

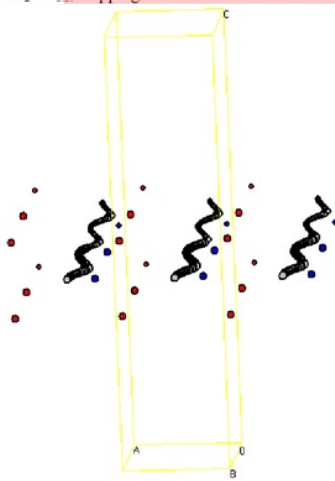


Figure 5. Pathway of oxide in equatorial site of perovskite-like layer. The pathway take places in tetrahedron coordination, with distance hopping oxide is 3.86 Å from O(3) to O(3) vacant.

In this model, oxygen ions are easier to move in [140] direction, which connect the O(3) with other O(3) with a

hopping distance of 3.86 Å. Along these pathways the maximum value of BVS is 4.472, and the minimum value is 1.320, i.e. within range of +223% to 66% from ideal value of 2. Merfelli *et al.* reported BVS of K^+ cation in KFeAs_2O_7 structure were within +197% (max BVS = 1.97) maximum and 89% (min BVS = 0.89) minimum [8]. Mazza reported that the maximum and minimum BVSeS of Na^+ cation were 1.4 and minimum 0.42, i.e. within range of 140 and 42% [7]. Thus, it could be seen that the range BVS values along the pathway are similar to those of other ion conductors. Oxygen ion migration parallel to *ab* plane is in agreement with that was proposed by Abraham and Krok [5], where a suitable pathway is available through vacant sites located in equatorial vanadate plane between four vanadium polyhedrals. The vacant site of vanadate layer is faced directly and coordinated linear to $\text{Bi } 6s^2$ lone pair orbital of $(\text{Bi}_2\text{O}_2)^{2+}$ layer. Interaction between layers of $(\text{Bi}_2\text{O}_2)^{2+}$ and vanadate in γ - $\text{Bi}_2\text{VO}_{5.5}$ is ionic. In this site, transient oxide ions can endure electrostatic repulsion, and due to well polarizability of the $\text{Bi } 6s^2$ lone pair orbital, so this route in equatorial site can avoid oxygen ions more close to vanadium ions [5].

This study suggests that the oxide is easier to migrate between equatorial site rather than from equatorial to apical or vice versa. The more realistic model of course is model with various coordinations in perovskite-like layers, namely tetrahedron, five-coordination, and octahedron. The result of ionic conductivity calculation in these models will be reported.

IV. CONCLUSION

Computational simulation of ionic conductivity of γ - $\text{Bi}_2\text{VO}_{5.5}$ has been performed using BVS method. Pathways of oxide conduction are within equatorial site on coordination environment of V-O. Oxide ions are easier to move on the [140] direction which is parallel to *ab* plane in perovskite-like layers, with minimum BVS of 1.320.

ACKNOWLEDGMENTS

This work was funded by riset kelompok keahlian Institut Teknologi Bandung (ITB) no. 043/K01.7/PL/2008 and no. 257/K01.7/PL/2009. ALK visit to Italy was funded by to Minister of National Education of Indonesia. Thanks also to D. Mazza at Dipartimento in Scienza dei Materiali e' Ingegneria Chimica (DISMIC), Politecnico di Torino for the opportunity to use Material Studio and JUMPITER.

REFERENCES

- [1] G. Mairesse, Bismuth-Based Oxide Conductors-Novel Structural and Electrochemical Features, *Kluwer Academic Publishers*, Netherlands, (1993)
- [2] P. Bruce, *Solid State Electrochemistry*, Cambridge University Press, UK, (1997)
- [3] E. Pémot, M. Anne, M. Bacmann, P. Strobel, J. Fouletier, R. N. Vannier, G. Mairesse, F. Abraham, and G. Nowogrocki, *Solid State Ionic*, 70/71 (1994) 259.
- [4] R. Kant, K. Singh, O. P. Pandey, *Int. J. Hydrogen Energy*, 33 (2008) 455–

**2011 International Conference on Instrumentation, Communication, Information Technology and Biomedical Engineering
8-9 November 2011, Bandung, Indonesia**

- 462.
- [5] I. Abrahams, F. Krok, *Solid State Ionics*, 157 (2003) 139–145.
- [6] Afifah, *et al.*, *J. Chin. Chem. Soc.*, 55, (2008), 115-120.
- [7] D. Mazza, *J. Solid State Chem.*, 156 (2001) 154-160.
- [8] N. Ouerfelli, A. Guesmi, P. Molinie, D. Mazza, M. F. Zid, and A. Drisset, *J. Solid State Chem.*, 180 (2007) 2942-2949.
- [9] D. Mazza, *JUMPITER Program*, Dipartimento di Scienza dei Material e Ingegneria Chimica, Politecnico di Torino, Italy, (2009).
- [10] G. Mairesse, P. Roussel, R. N. Vannier, M. Anne, C. Pirovano, G. Nowogrocki, *Solid State Sci.*, 5 (2003) 851–859.
- [11] F. Krok, I. Abrahams, A. Zadrozna, M. Malys, W. Bogusz, J. A. G. Nelstrop, A. J. Bush, *Solid State Ionics*, 119 (1999) 139–144.
- [12] G. Mairesse, *C.R. Academicof Science, Paris*, t.2, Serie IIc, (1999) 651-660.
- [13] V. I. Voronkova, V. K. Yanovskii, E. P. Kharitonova, and O. G. Rudnitskaya, *Inorg. Mater.*, 41, 7, 760–765 (2005), translated from *Neorg. Mater.*, 41 (2005) 866-870.
- [14] O. Joubert, A. Jouanneaux, M. Ganne, R. N. Vannier, and G. Mairesse, *Solid State Ionics*, 73 (1994) 309.

Modeling ionic conduction

ORIGINALITY REPORT

96%

SIMILARITY INDEX

6%

INTERNET SOURCES

96%

PUBLICATIONS

43%

STUDENT PAPERS

PRIMARY SOURCES

- 1** Akram La Kilo, Bambang Prijamboedi, Muhamad A. Martoprawiro, Ismunandar. "Modeling ionic conduction in γ -Bi₂VO_{5.5}", 2011 2nd International Conference on Instrumentation, Communications, Information Technology, and Biomedical Engineering, 2011
Publication 92%
 - 2** Submitted to School of Business and Management ITB
Student Paper 3%
 - 3** Submitted to Universiti Kebangsaan Malaysia
Student Paper 2%
-

Exclude quotes On

Exclude matches Off

Exclude bibliography On